



LOW-VOLTAGE QUADRUPLE BUS SWITCH

IDT74CBTLV3125

FEATURES:

- Pin-out compatible with standard '125 Logic products
- 5Ω A/B bi-directional bus switch
- Isolation under power-off conditions
- Over-voltage tolerant
- Latch-up performance exceeds 100mA
- $V_{CC} = 2.3V - 3.6V$, Normal Range
- ESD > 2000V per MIL-STD-883, Method 3015;
> 200V using machine model (C = 200pF, R = 0)
- Available in QSOP and TSSOP packages

APPLICATIONS:

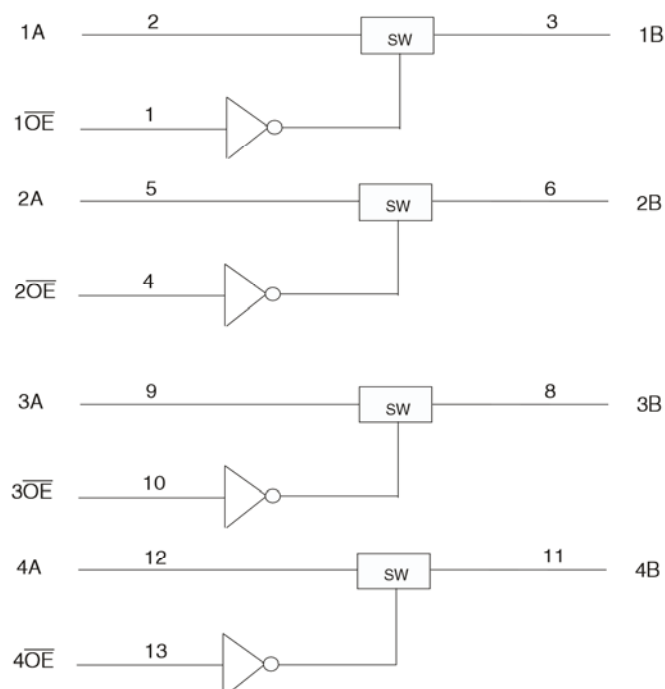
- 3.3V High Speed Bus Switching and Bus Isolation

DESCRIPTION:

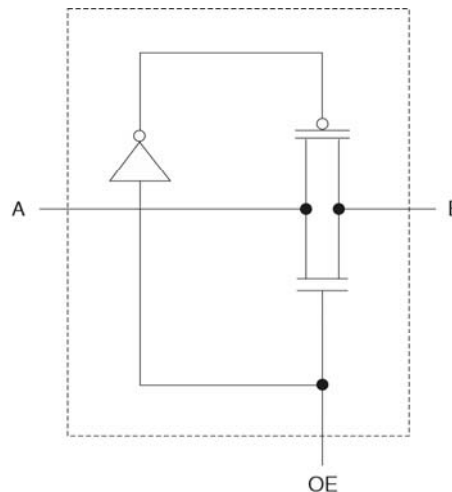
The CBTLV3125 features four independent switches. Each switch is enabled when the associated output-enable ($\overline{OE}$) input is low.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

FUNCTIONAL BLOCK DIAGRAM



SIMPLIFIED SCHEMATIC, EACH SWITCH



NOTE:

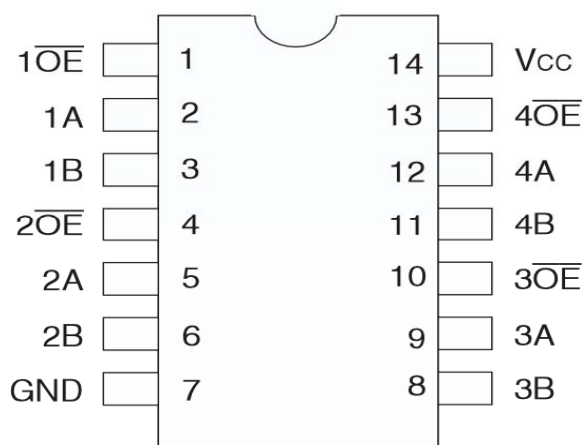
1. Pin numbers shown apply to the 14-pin TSSOP package.

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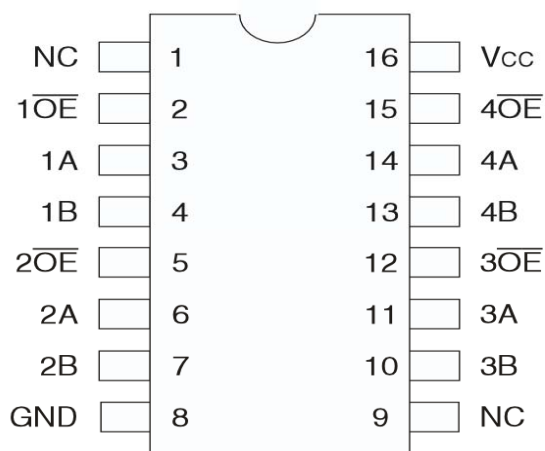
INDUSTRIAL TEMPERATURE RANGE

DECEMBER 2014

PIN CONFIGURATION



TSSOP
TOP VIEW



QSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
V _{CC}	Supply Voltage Range	−0.5 to +4.6	V
V _I	Input Voltage Range	−0.5 to +4.6	V
	Continuous Channel Current	128	mA
I _{IK}	Input Clamp Current, V _{I/O} < 0	−50	mA
T _{STG}	Storage Temperature	−65 to +150	°C

NOTE:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

FUNCTION TABLE⁽¹⁾

Input $\overline{OE}$	Inputs/Outputs
L	A Port = B Port
H	Disconnect

NOTE:

1. H = HIGH Voltage Level
L = LOW Voltage Level

OPERATING CHARACTERISTICS, T_A = 25°C⁽¹⁾

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
V _{CC}	Supply Voltage		2.3	3.6	V
V _{IH}	High-Level Control Input Voltage	V _{CC} = 2.3V to 2.7V	1.7	—	V
		V _{CC} = 2.7V to 3.6V	2	—	
V _{IL}	Low-Level Control Input Voltage	V _{CC} = 2.3V to 2.7V	—	0.7	V
		V _{CC} = 2.7V to 3.6V	—	0.8	
T _A	Operating Free-Air Temperature		−40	85	°C

NOTE:

1. All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Conditions: $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
V_{IK}	Control Inputs, Data Inputs	$V_{CC} = 3\text{V}$, $I_I = -18\text{mA}$		—	—	-1.2	V
I_I	Control Inputs	$V_{CC} = 3.6\text{V}$, $V_I = V_{CC}$ or GND		—	—	± 1	μA
I_{OZ}	Data I/O	$V_{CC} = 3.6\text{V}$, $V_O = 0$ or 3.6V , switch disabled		—	—	5	μA
I_{OFF}		$V_{CC} = 0$, V_I or $V_O = 0$ to 3.6V		—	—	50	μA
I_{CC}		$V_{CC} = 3.6\text{V}$, $I_O = 0$, $V_I = V_{CC}$ or GND		—	—	10	μA
$\Delta I_{CC}^{(2)}$	Control Inputs	$V_{CC} = 3.6\text{V}$, one input at 3V , other inputs at V_{CC} or GND		—	—	300	μA
C_I	Control Inputs	$V_I = 3\text{V}$ or 0		—	4	—	pF
$C_{IO(OFF)}$		$V_O = 3\text{V}$ or 0 , $\overline{OE} = V_{CC}$		—	6	—	pF
$R_{ON}^{(3)}$	$V_{CC} = 2.3\text{V}$ Typ. at $V_{CC} = 2.5\text{V}$	$V_I = 0$	$I_O = 64\text{mA}$	—	5	8	Ω
			$I_O = 24\text{mA}$	—	5	8	
	$V_{CC} = 3\text{V}$	$V_I = 1.7\text{V}$	$I_O = 15\text{mA}$	—	27	40	
			$I_O = 64\text{mA}$	—	5	7	
		$V_I = 0$	$I_O = 24\text{mA}$	—	5	7	
			$I_O = 15\text{mA}$	—	10	15	

NOTES:

- Typical values are at $V_{CC} = 3.3\text{V}$, $+25^{\circ}\text{C}$ ambient.
- The increase in supply current is attributable to each current that is at the specified voltage level rather than V_{CC} or GND.
- This is measured by the voltage drop between the A and B terminals at the indicated current through the switch.

SWITCHING CHARACTERISTICS

Symbol	Parameter	$V_{CC} = 2.5\text{V} \pm 0.2\text{V}$		$V_{CC} = 3.3\text{V} \pm 0.3\text{V}$		Unit
		Min.	Max.	Min.	Max.	
$t_{PD}^{(1)}$	Propagation Delay A to B or B to A	—	0.15	—	0.25	ns
t_{EN}	Output Enable Time $\overline{OE}$ to A or B	1	4.6	1	4.4	ns
t_{DIS}	Output Disable Time $\overline{OE}$ to A or B	1	3.9	1	4.2	ns

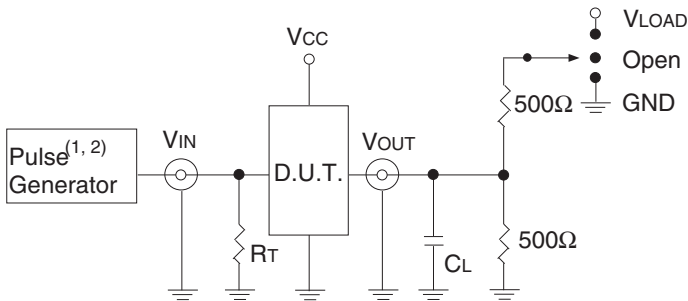
NOTE:

- The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance driven by an ideal voltage source (zero output impedance).

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$V_{CC}^{(1)} = 3.3V \pm 0.3V$	$V_{CC}^{(2)} = 2.5V \pm 0.2V$	Unit
V_{LOAD}	6	$2 \times V_{CC}$	V
V_{IH}	3	V_{CC}	V
V_T	1.5	$V_{CC} / 2$	V
V_{LZ}	300	150	mV
V_{HZ}	300	150	mV
C_L	50	30	pF



Test Circuits for All Outputs

DEFINITIONS:

C_L = Load capacitance: includes jig and probe capacitance.

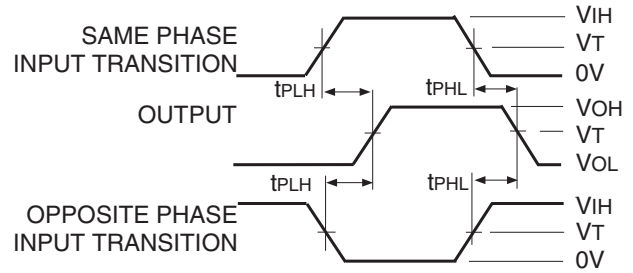
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:

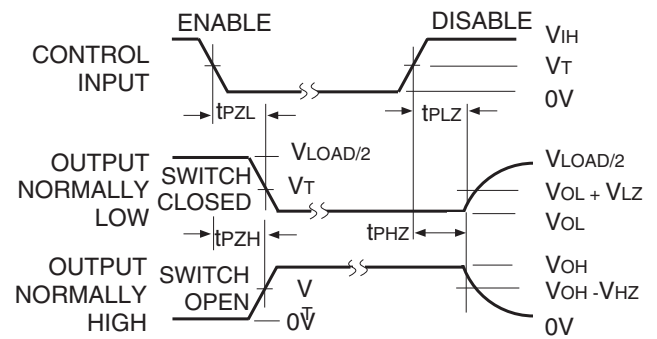
1. Pulse Generator for All Pulses: Rate $\leq 10\text{MHz}$; $t_r \leq 2.5\text{ns}$; $t_f \leq 2.5\text{ns}$.
2. Pulse Generator for All Pulses: Rate $\leq 10\text{MHz}$; $t_r \leq 2\text{ns}$; $t_f \leq 2.5\text{ns}$.

SWITCH POSITION

Test	Switch
t_{PLZ}/t_{PZL}	V_{LOAD}
t_{PHZ}/t_{PZH}	GND
t_{PD}	Open



Propagation Delay



Enable and Disable Times

ORDERING INFORMATION

XX	CBTLV	XXX	XX	X	
Temp. Range		Device Type	Package		
				Blank 8	Tube or Tray Tape and Reel
				QG PGG	Quarter-size Small Outline Package - Green Thin Shrink Small Outline Package - Green
				3125	Low-Voltage Quadruple Bus Switch
				74	−40°C to +85°C

Datasheet Document History

07/14/2008	Pg. 1	Updated IDT Logo.
12/04/2014	Pg. 5	Updated the ordering information by removing the "IDT" notation, non RoHS part and by adding Tape and Reel information.



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